Checks of APD matrix & Prague 16ch. preamplifier

- 1. Cross talk between pixels
- 2. Homogeneity of response from pixels
- 3. Minical beam tests

APD:	Hamamatsu matrix S8550 with 32 pixels
Preampli:	16 channel voltage preamp on PCB
Light:	pulsed LEDs at 1 kHz
Signal:	triggered at 350 ns gate sent to ADC

Done mainly by S. Němeček, J. Zálešák, I. Polák, Institute of Physics AS CR, Prague

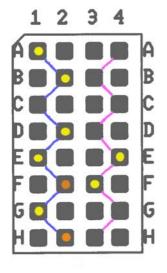
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Measurement set-up

APD matrix

LED

LED pulses from preamp

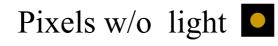


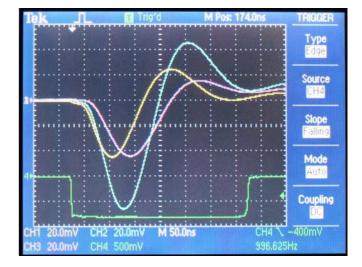
3 LED (A, C, D)

LED A, D - 3 fibres LED C -1 fibre

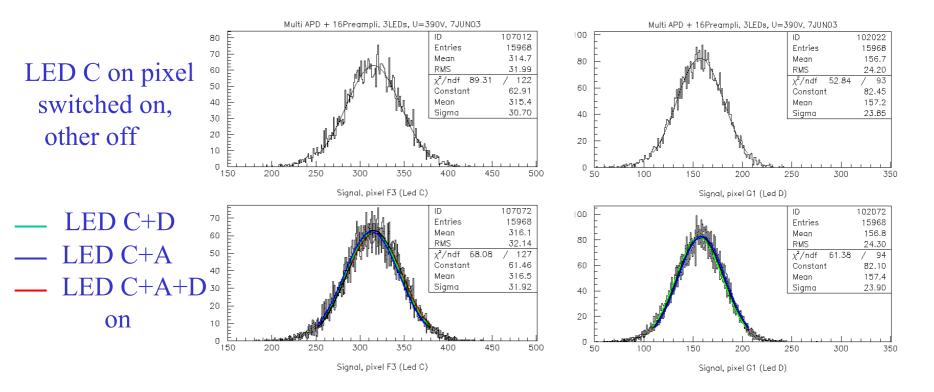
Pixels with light

pixels withsame bias V





Cross talk for pixels F3, G1

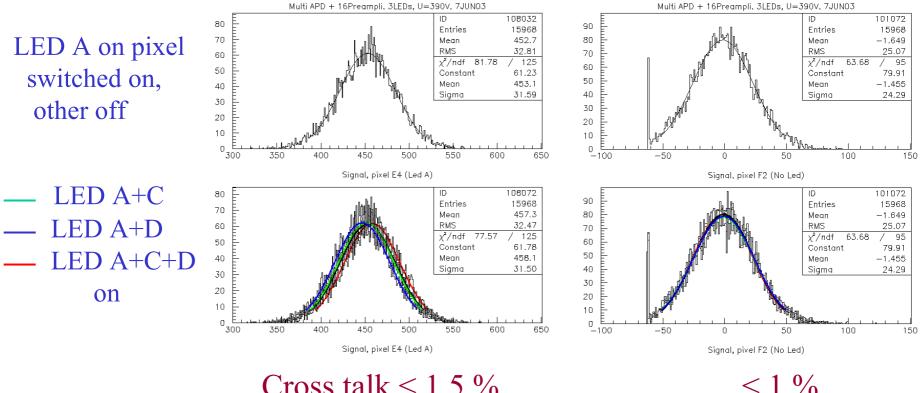


Cross talk between pixels < 1 %

Cross talk for pixels E4, F2

Pixel with light

Pixel without light



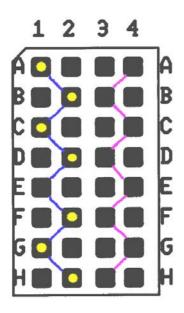
Cross talk < 1.5 %

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J. Cvach: APD & preamp

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Homogeneity of response from pixels



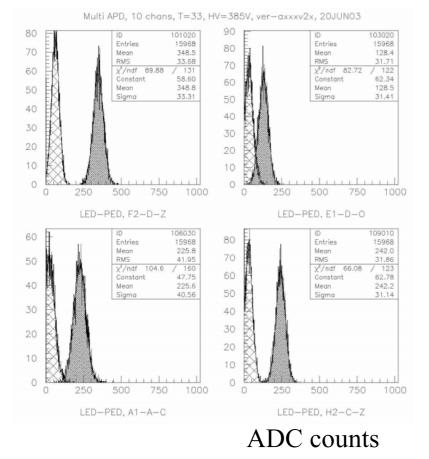
3 LED with 3+3+1 fibres used periodically on 8 APD pixels at the same bias V (left half) at the same temperature (~33 deg C)

Signals measured for:

- Reproducibility
- LED light intensity in fibres
- Signal levels from different pixels

Results

Signals & pedestals from APD pixels



• Reproducibility of the signal s

measurement:
$$\langle \frac{s1-s2}{s1} \rangle = (0\pm 33)\%$$

But temperature during measurements 32-33°C: relative gain error ~ 15%

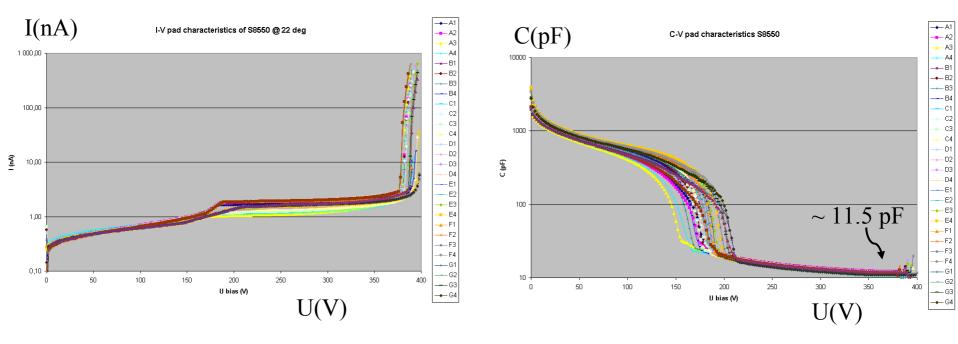
3 fibres from the same LED give relative signals <over 8 pixels>:
LED-fibre relative signal
A-H 0.56+-0.28
A-Z 1.00
A-C 1.36+-0.47

Our plans for beam tests

- APD single channel (and matrix S8550) with
- Prague 16 channel preamp board and
- new board with Orsay 18 ch. preamp chip (PCB design done by Milan Janata in Prague)
- Backup with 16 channel PMTs (SV + JW) we plan to be at DESY – weeks 32-34 (August) good news – 20 single channel APDs delivered last Friday in customs in Prague – available for tests this week ??

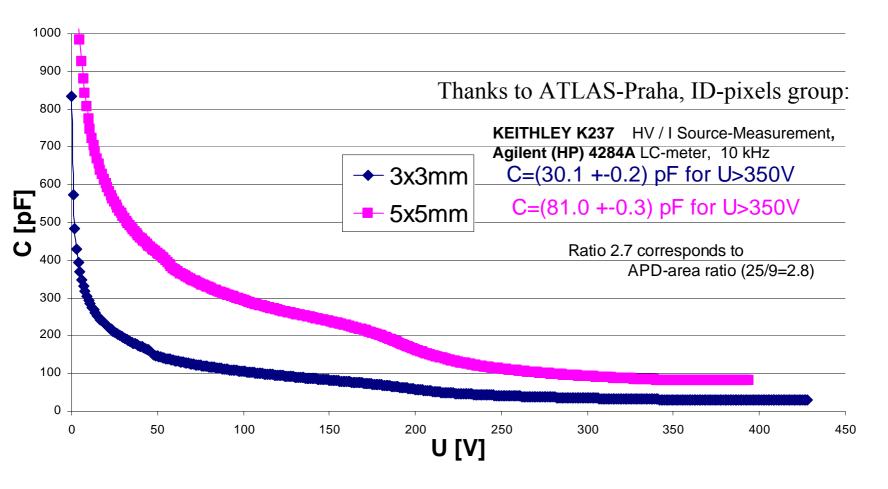
What to measure with new APDs?

1. Current and capacitance vs. bias voltage



Results for APD matrix S8550

C-V characteristics of APD

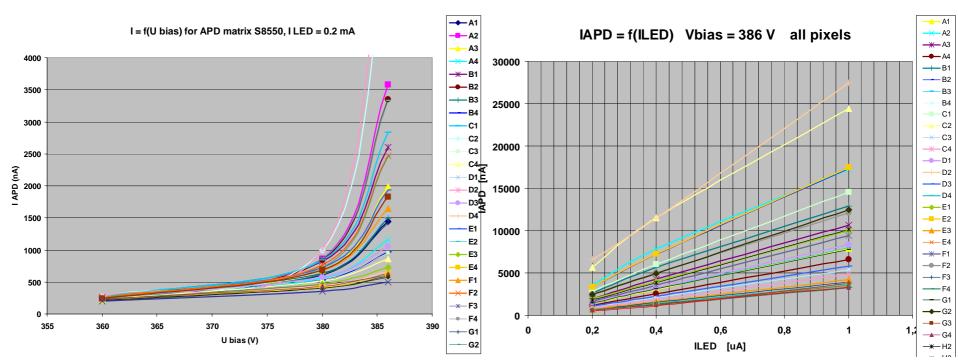


From ECFA-DESY in Amsterdam 2003, J. Němeček: Photodectors for TileHCAL prototype

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APD response to LED light

$$I_{APD} = f(I_{LED})$$



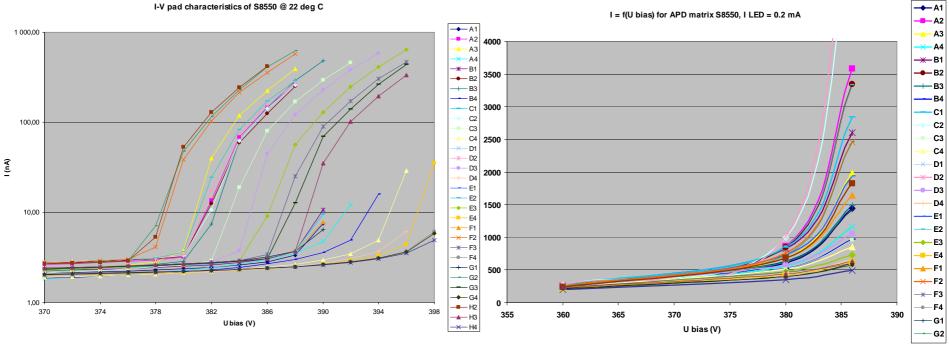
Done for all pixels of APD matrix

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 $I_{APD} = f(U_{bias})$

Two methods of measurements of APD current

Passive: I-U characteristics Keithley K237 HV source HP 4284A LC meter Active: I_{APD} as function of V_{bias} and I_{LED} Keithley 6514 electrometer



Dark current measurements

"Gain" measurements

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Working point for each APD

Gain measurement for one pixel of a matrix

M (DC gain) APD S8550 - pixel D4, 23 deg C 1 000 100000 10000 **Dark current (nA)** 1000 100 ≥ 100 10 10 → M gain Dark current nA 75 175 225 275 325 375 25 125

HV bias [V]

- Gain measurement for each APD illuminated by LED (bias 40-420V)
- Choose a common (same for all APDs) gain
- Set bias HV by setting for each APD corresponding HV
- Suitable PCB for this was developed in Prague

Conclusions

with respect to minical tests

- Single channel APD should be tested at the same temperature and selected those with similar gain
- PCB is produced in Prague which allows to set (one) bias voltage for each APD – advantage compared to APD matrix (one bias voltage for 16 pixels)
- Preampli: our 16 ch. voltage preampli stable in operation PCB with 16 single channel APDs can be fixed on top of the board (2 boards exist)
- New board for 18 ch. Orsay chip being developed in Prague
- Gilitski preampli?
- Works on temperature stabilized box for measurements of APD characteristics and temperature sensitive HV source for APDs is under development in Prague